

60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE INTELLIFET[®] MOSFET WITH PROGRAMMABLE CURRENT LIMIT
Product Summary

- Continuous Drain Source Voltage $V_{DS} = 60V$
- On-State Resistance 500m Ω
- Nominal Load Current ($V_{IN} = 5V$) 1.4A
- Clamping Energy 550mJ

Description

Self protected low side MOSFET. Monolithic over temperature, over current, over voltage (active clamp) and ESD protected logic level functionality. Intended as a general purpose switch, with status indication and programmable current limit.

Applications

- Especially suited for loads with a high in-rush current such as lamps and motors
- All types of resistive, inductive and capacitive loads in switching applications
- μC compatible power switch for 12V and 24V DC applications.
- Automotive rated
- Replaces electromechanical relays and discrete circuits
- Linear mode capability - the current-limiting protection circuitry is designed to de-activate at low V_{DS} , in order not to compromise the load current during normal operation. The design max. DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry.
- **Note:** This does not compromise the product's ability to self-protect during short-circuit load conditions
- The current limit is programmable via an external resistor R_{prog} connected between Status and IN pins
- Status pin voltage reflects the gate drive being applied internally to the power MOSFET
- With $V_{IN} = 5V$ and $R_{prog} = 24k\Omega$:
 - Status voltage: 5V indicates normal operation.
 - Status voltage: (2-3)V indicates that the device is in current-limiting mode.
 - Status voltage < 1V indicates that the device is in thermal shutdown.

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q100 qualified and are PPAP capable. Automotive, AEC-Q100 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

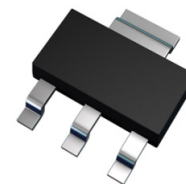
Features and Benefits

- Current Limit Programmable Via External Resistor
- Status Pin (analog status indication)
- Logic Level Input
- Short Circuit Protection with Auto Restart
- Over Voltage Protection (active clamp)
- Thermal Shutdown with Auto Restart
- Over-Current Protection
- Input Protection (ESD)
- Load Dump Protection (actively protects load)
- High Continuous Current Rating
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable**
- **Lead-Free Finish; RoHS compliant (Note 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

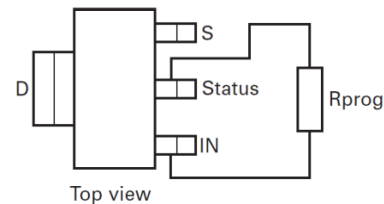
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.112 grams (approximate)

SOT223



Top View

 Note: R_{PROG} must be connected between the Status and IN pins


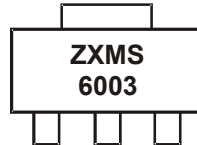
Top view

Ordering Information (Note 5)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMS6003GQTA	ZXMS6003	7	12	1,000 units

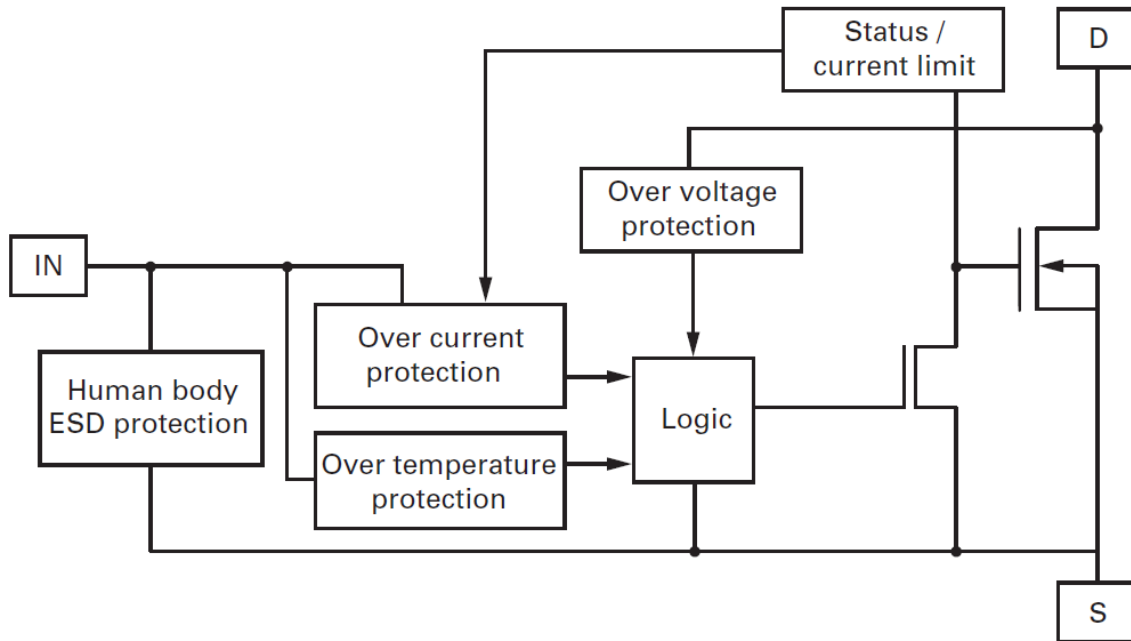
Note: 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZXMS6003 = Product type Marking Code

Functional Block Diagram



Absolute Maximum Ratings (@ $T_{AMB} = +25^{\circ}\text{C}$, unless otherwise stated.)

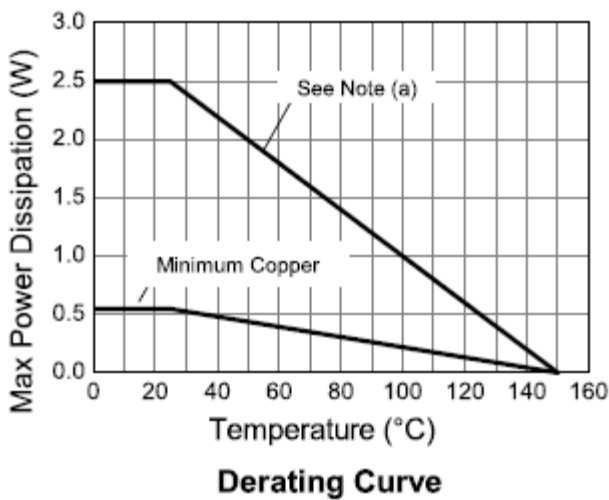
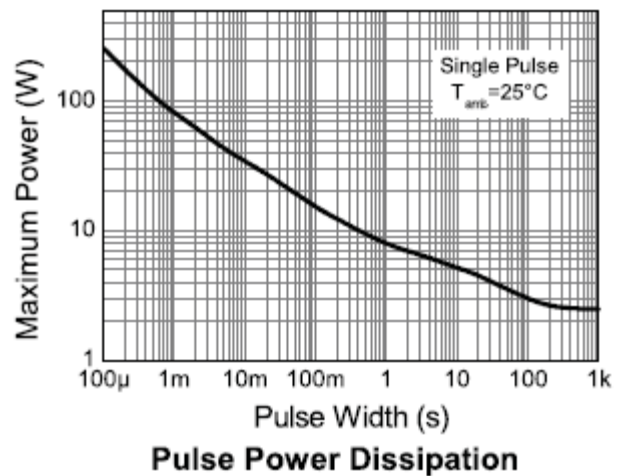
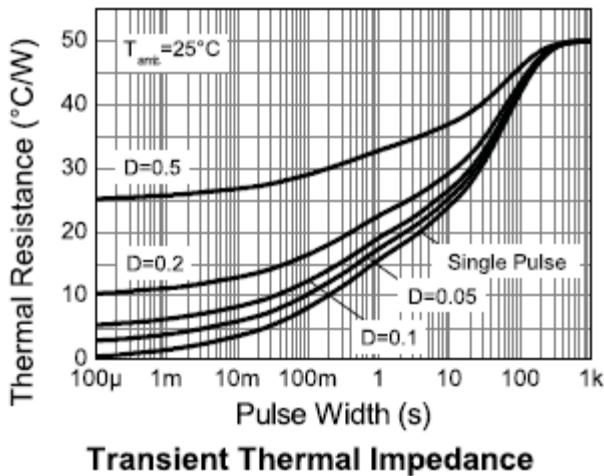
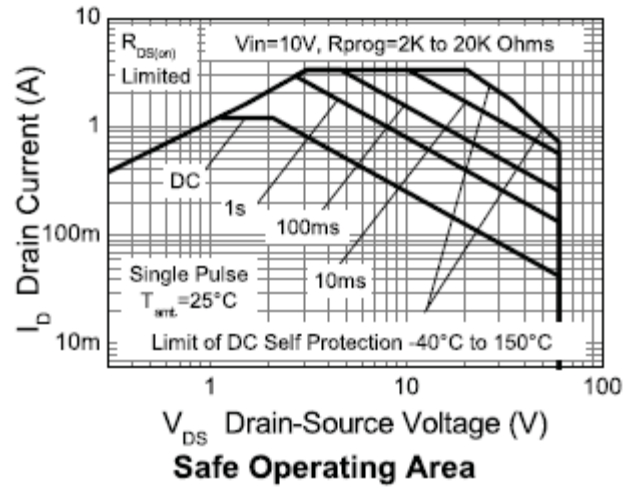
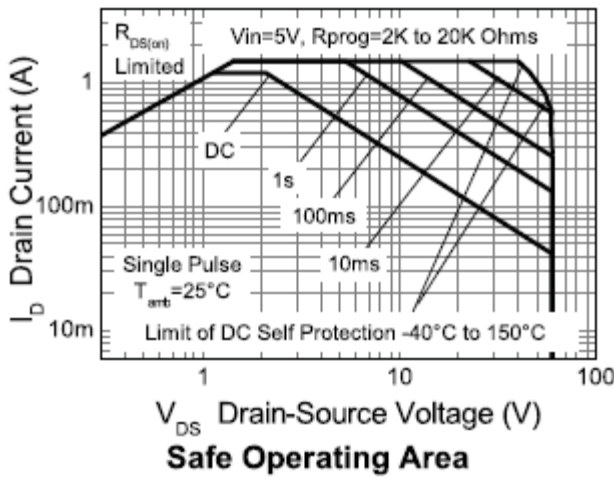
Parameter	Symbol	Limit	Unit
Continuous Drain-Source Voltage	V_{DS}	60	V
Drain-Source Voltage for Short Circuit Protection $V_{IN} = 5\text{V}$ (Note 6)	$V_{DS(SC)}$	36	V
Drain-Source Voltage for Short Circuit Protection $V_{IN} = 10\text{V}$ (Note 6)	$V_{DS(SC)}$	20	V
Continuous Input Voltage	V_{IN}	-0.2 to +10	V
Peak Input Voltage	V_{IN}	-0.2 to +20	V
Operating Temperature Range	T_J	-40 to +150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^{\circ}\text{C}$
Power Dissipation at $T_{AMB} = +25^{\circ}\text{C}$ ^(a) (Note 6)	P_D	2.5	W
Continuous Drain Current @ $V_{IN} = 10\text{V}$; $T_A = +25^{\circ}\text{C}$ (Note 7)	I_D	1.6	A
Continuous Drain Current @ $V_{IN} = 5\text{V}$; $T_A = +25^{\circ}\text{C}$ (Note 7)	I_D	1.4	A
Continuous Source Current (Body Diode) (Note 7)	I_S	3	A
Pulsed Source Current (Body Diode) (Note 8)	I_S	8	A
Unclamped Single Pulse Inductive Energy	E_{AS}	550	mJ
Load Dump Protection	$V_{LoadDump}$	80	V
Electrostatic Discharge (Human Body Model)	V_{ESD}	4000	V
DIN Humidity Category, DIN 40 040		E	
IEC Climatic Category, DIN IEC 68-1		40/150/56	

Thermal Resistance (@ $T_{AMB} = +25^{\circ}\text{C}$, unless otherwise stated.)

Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	50	$^{\circ}\text{C}/\text{W}$
Junction to Ambient	$R_{\theta JA}$	28	$^{\circ}\text{C}/\text{W}$

- Notes:
6. For $I_{D(LIM)} < 1.2\text{A}$ (see safe operating area curve).
 7. For a device surface mounted on 50mm x 50mm x 1.6mm FR4 board with a high coverage of single sided 2oz weight copper.
 8. For a device surface mounted on FR4 board and measured at $t < 10\text{s}$.

Thermal Characteristics

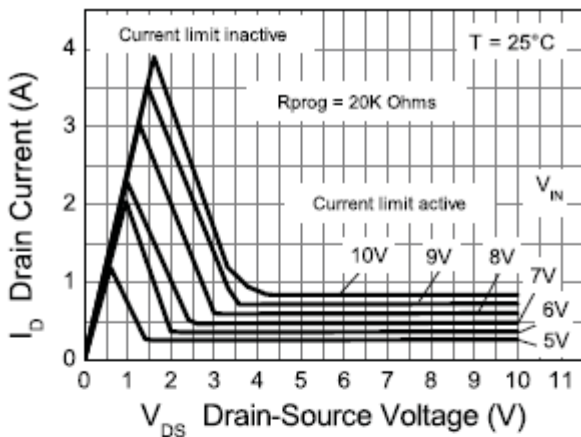


Electrical Characteristics (@ $T_{amb} = +25^{\circ}\text{C}$, unless otherwise stated.)

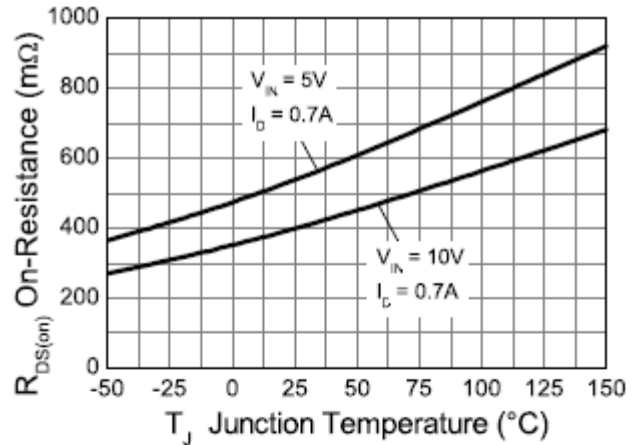
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Static Characteristics						
Drain-Source Clamp Voltage	$V_{DS(AZ)}$	60	70	75	V	$I_D = 10\text{mA}$
Off State Drain Current	I_{DSS}	—	0.1	3	μA	$V_{DS} = 12\text{V}, V_{IN} = 0\text{V}$
Off State Drain Current	I_{DSS}	—	3	15	μA	$V_{DS} = 32\text{V}, V_{IN} = 0\text{V}$
Input Threshold Voltage (Note 9)	$V_{IN(th)}$	1	2.1	—	V	$V_{DS} = V_{GS}, I_D = 1\text{mA}$
Input Current	I_{IN}	—	0.7	1.2	mA	$V_{IN} = +5\text{V}$
Input Current	I_{IN}	—	1.5	2.7	mA	$V_{IN} = +7\text{V}$
Input Current	I_{IN}	—	4	7	mA	$V_{IN} = +10\text{V}$
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	—	520	675	$\text{m}\Omega$	$V_{IN} = 5\text{V}, I_D = 0.2\text{A}$
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	—	385	500	$\text{m}\Omega$	$V_{IN} = 10\text{V}, I_D = 0.5\text{A}$
Current Limit (Note 10)	$I_{D(LIM)}$	0.2	0.3	0.4	A	$V_{IN} = 5\text{V}, V_{DS} = 10\text{V}, R_{PROG} = 20\text{k}$
Current Limit (Note 10)	$I_{D(LIM)}$	0.7	0.9	1.2	A	$V_{IN} = 10\text{V}, V_{DS} = 10\text{V}, R_{PROG} = 20\text{k}$
Dynamic Characteristics						
Turn-On Time (V_{IN} to 90% I_D)	t_{ON}	—	3	10	μs	$R_{PROG} = 20\text{k}, R_L = 22\Omega, V_{IN} = 0$ to 10V, $V_{DD} = 12\text{V}$
Turn-Off Time (V_{IN} to 90% I_D)	T_{OFF}	—	13	20	μs	$R_{PROG} = 20\text{k}, R_L = 22\Omega, V_{IN} = 10\text{V}$ to 0V, $V_{DD} = 12\text{V}$
Slew Rate On (70 to 50% V_{DD})	DV_{DS}/dt_{ON}	—	8	20	V/ μs	$R_{PROG} = 20\text{k}, R_L = 22\Omega, V_{IN} = 0$ to 10V, $V_{DD} = 12\text{V}$
Slew Rate Off (50 to 70% V_{DD})	DV_{DS}/dt_{ON}	—	3.2	10	V/ μs	$R_{PROG} = 20\text{k}, R_L = 22\Omega, V_{IN} = 10\text{V}$ to 0V, $V_{DD} = 12\text{V}$
Protection Functions (Note 10)						
Required Input Voltage for Over Temperature Protection	V_{PROT}	4.5	—	—	V	
Thermal Overload Trip Temperature	T_{JT}	150	175	—	$^{\circ}\text{C}$	
Thermal hysteresis	—	—	1	—	$^{\circ}\text{C}$	
Unclamped Single Pulse Inductive Energy $T_J = +25^{\circ}\text{C}$	E_{AS}	550	—	—	mJ	$I_{D(ISO)} = 0.7\text{A}, V_{DD} = 32\text{V}$
Unclamped Single Pulse Inductive Energy $T_J = +150^{\circ}\text{C}$	E_{AS}	200	—	—	mJ	$I_{D(ISO)} = 0.7\text{A}, V_{DD} = 32\text{V}$
Status Flag						
Normal Operation	V_{STATUS}	—	4.95	—	V	$V_{IN} = 5\text{V}$
Current Limit Operating	V_{STATUS}	—	2.5	—	V	$V_{IN} = 5\text{V}$
Thermal Shutdown Activated	V_{STATUS}	—	0.2	1	V	$V_{IN} = 5\text{V}$
Normal Operation	V_{STATUS}	—	8	—	V	$V_{IN} = 10\text{V}$
Current Limit Operation	V_{STATUS}	—	3	—	V	$V_{IN} = 10\text{V}$
Thermal Shutdown Activated	V_{STATUS}	—	0.35	1	V	$V_{IN} = 10\text{V}$
Inverse Diode						
Source Drain Voltage	V_{SD}	—	—	1	V	$V_{IN} = 0\text{V}, -I_D = 1.4\text{A}$,

- Notes:
9. Protection features may operate outside spec for $V_{IN} < 4.5\text{V}$
 10. The drain current is limited to a reduced value when V_{ds} exceeds a safe level.
 11. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the datasheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous, repetitive operation.

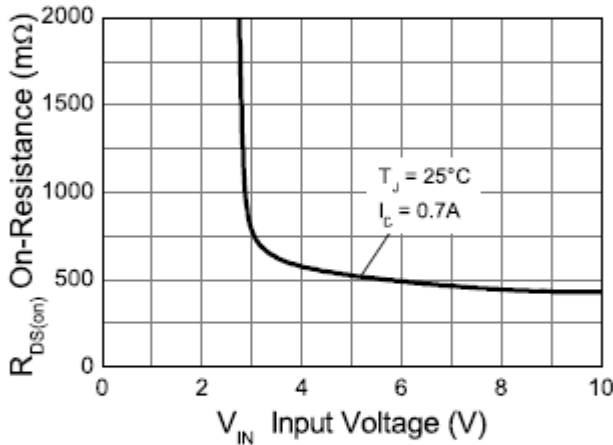
Typical Characteristics



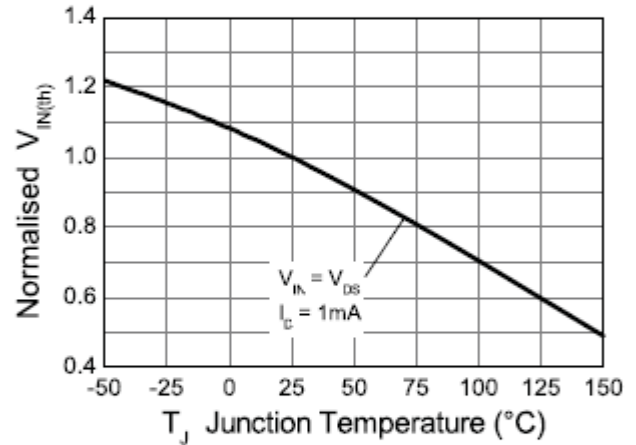
Typical Output Characteristic



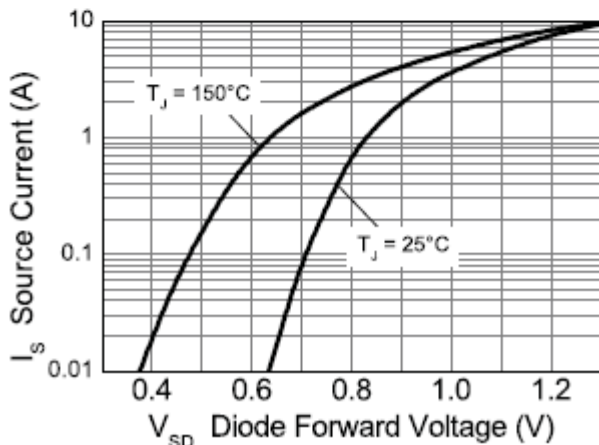
On-state Resistance vs Temperature



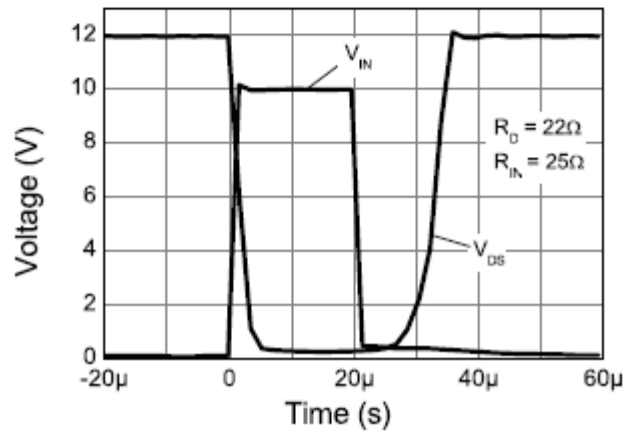
On-Resistance vs Input Voltage



Threshold Voltage vs Temperature

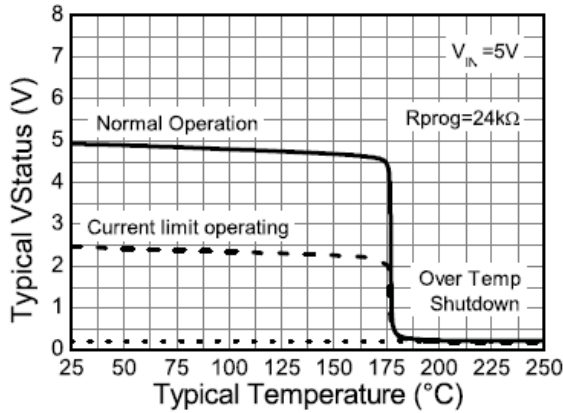


Source-Drain Diode Forward Voltage

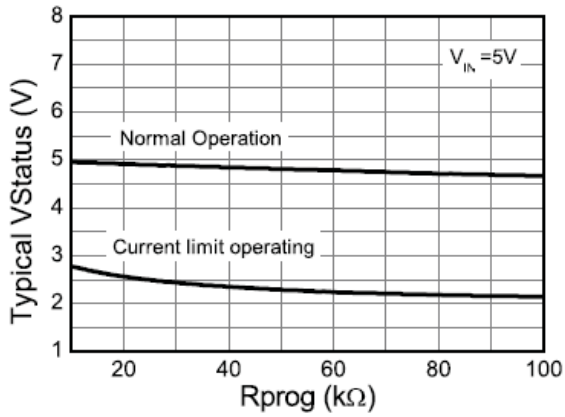
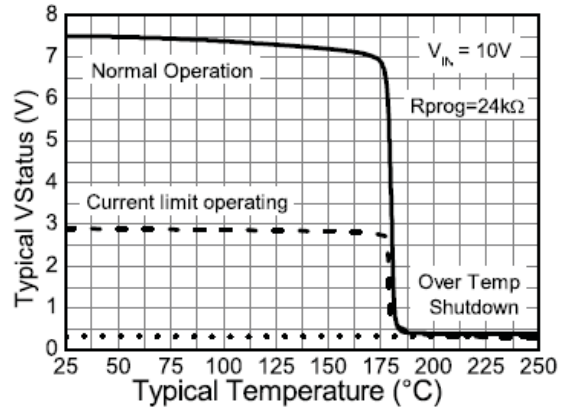


Switching Speed

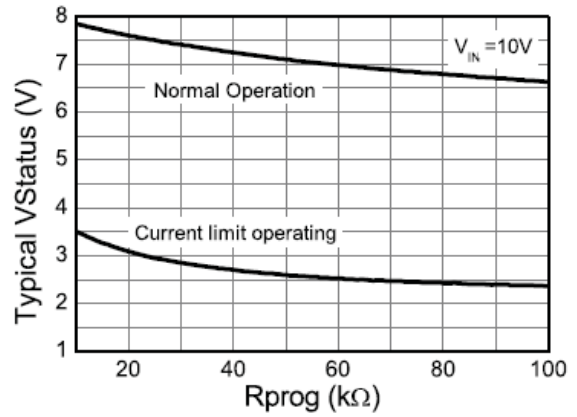
Current Limiting and Over Temp Shutdown Status Indication at Vin=5V



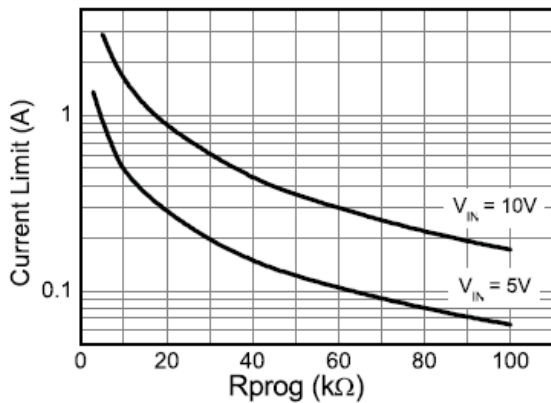
Current Limiting and Over Temp Shutdown Status Indication at Vin=10V



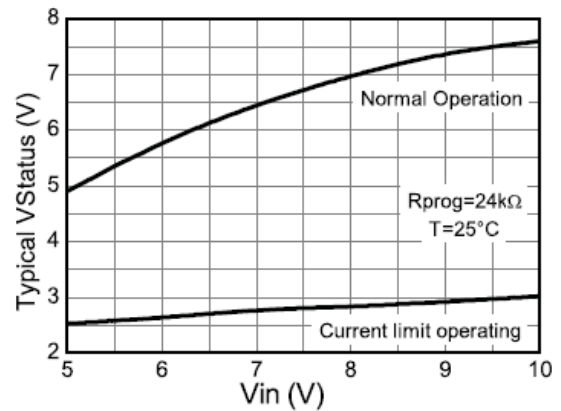
VStatus vs Rprog @ Vin=5V



VStatus vs Rprog @ Vin=10V



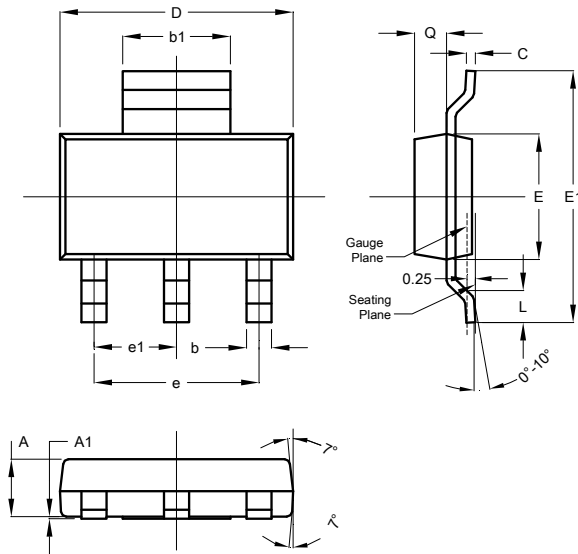
Current Limit vs Rprog



VStatus vs Vin

Package Outline Dimensions

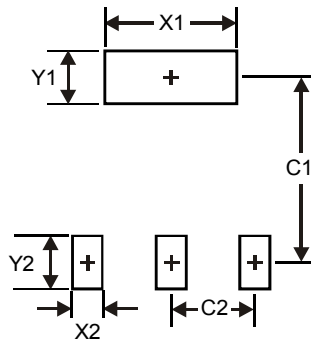
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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